

2N2905AHR

Hi-Rel PNP bipolar transistor 60 V - 0.6 A

Features

BV _{CEO}	60 V
I _C (max)	0.6 A
H _{FE} at 10 V - 150 mA	> 100
Operating temperature range	-65°C to +200°C

- Hi-Rel PNP bipolar transistor
- Linear gain characteristics
- ESCC qualified
- European preferred part list EPPL
- Radiation level: lot specific total dose contact marketing for specified level

Description

The 2N2905AHR is a silicon planar epitaxial PNP transistors in TO-39 package. It is specifically designed for aerospace Hi-Rel applications and ESCC qualified according to the 5202-002 specification. In case of conflict between this datasheet and ESCC detailed specification, the latter prevails.

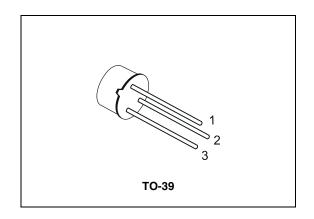


Figure 1. Internal schematic diagram

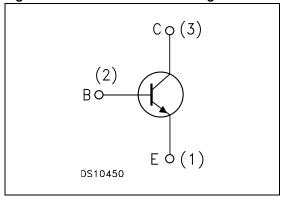


Table 1. Device summary

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Order codes	Package	Lead finish	Marking	Туре	EPPL	Packaging
2N2905AHR	TO-39	Gold Solder Dip	520200201 520200202	ESCC Flight	Yes	Strip pack
2N2905AHR	TO-39	Gold	2N2905AT1	Engineering model		Strip pack

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Electrical ratings 2N2905AHR

1 Electrical ratings

Table 2. Absolute maximum ratings

Symbol	Parameter	Value	Unit
V _{CBO}	Collector-base voltage (I _E = 0)	-60	V
V _{CEO}	Collector-emitter voltage (I _B = 0)	-60	V
V _{EBO}	Emitter-base voltage (I _C = 0)	-5	V
I _C	Collector current	-0.6	Α
P _{TOT}	Total dissipation at $T_{amb} \le 25 ^{\circ}\text{C}$ Total dissipation at $T_{c} \le 25 ^{\circ}\text{C}$	0.6 3	W W
T _{STG}	Storage temperature	-65 to 200	°C
TJ	Max. operating junction temperature	200	°C

Table 3. Thermal data

Symbol	Parameter	Value	Unit	
R _{thJC}	Thermal resistance junction-case	max	58	°C/W
R_{thJA}	Thermal resistance junction-ambient ma		291	°C/W

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2 Electrical characteristics

 T_{case} = 25 °C unless otherwise specified.

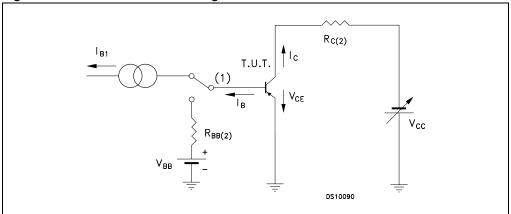
Table 4. Electrical characteristics

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
I _{CBO}	Collector-base cut-off current (I _E = 0)	V _{CB} = -50 V V _{CB} = -50 V T _C = 150 °C			-10 -10	nΑ μΑ
V _{(BR)CBO}	Collector-base breakdown voltage (I _E = 0)	I _C = -10 μA	-60			٧
V _{(BR)CEO} (1)	Collector-emitter breakdown voltage (I _B = 0)	I _C = -10 mA	-60			٧
V _{(BR)EBO}	Emitter-base breakdown voltage (I _C = 0)	I _E = -10 μA	-5			٧
V _{CE(sat)} (1)	Collector-emitter saturation voltage	I _C = -150 mA I _B = -15 mA			-0.4	V
V _{BE(sat)} (1)	Base-emitter saturation voltage	I _C = -150 mA I _B = -15 mA			-1.3	V
h _{FE} ⁽¹⁾	DC current gain	$\begin{split} & I_{C} = -0.1 \text{ mA} & V_{CE} = -10 \text{ V} \\ & I_{C} = -1 \text{ mA} & V_{CE} = -10 \text{ V} \\ & I_{C} = -150 \text{ mA} & V_{CE} = -10 \text{ V} \\ & I_{C} = -500 \text{ mA} & V_{CE} = -10 \text{ V} \end{split}$	75 100 100 50		300	
h _{fe}	Small signal current gain	$V_{CE} = -20 \text{ V}$ $I_{C} = -50 \text{ mA}$ $f = 100 \text{ MHz}$	2			
C _{CBO}	Output capacitance (I _E = 0)	$V_{CB} = -10 \text{ V}$ 100 kHz $\leq f \leq 1 \text{ MHz}$			8	pF
t _{on}	Turn-on time	$V_{CC} = -30 \text{ V}$ $I_{C} = -150 \text{ mA}$ $I_{B1} = -15 \text{ mA}$			45	ns
t _{off}	Turn-off time	$V_{CC} = -30 \text{ V}$ $I_{C} = -150 \text{ mA}$ $I_{B1} = -I_{B2} = -15 \text{ mA}$			300	ns

^{1.} Pulsed duration = 300 µs, duty cycle ≤ 1.5%

2.1 Test circuit

Figure 2. Resistive load switching test circuit



- 1. Fast electronic switch
- 2. Non-inductive resistor



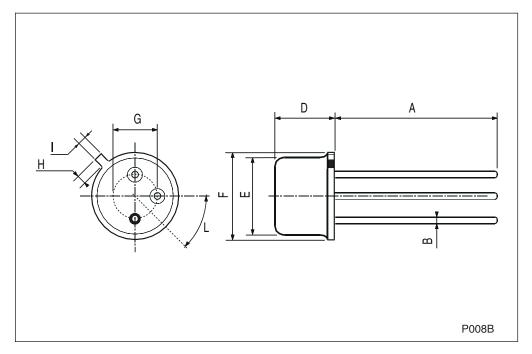
3 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of $\mathsf{ECOPACK}^{\mathbb{B}}$ packages, depending on their level of environmental compliance. $\mathsf{ECOPACK}^{\mathbb{B}}$ specifications, grade definitions and product status are available at: $\mathit{www.st.com}$. $\mathsf{ECOPACK}^{\mathbb{B}}$ is an ST trademark.



TO-39 Mechani	cai c	ıata
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DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
Α	12.7			0.500		
В			0.49			0.019
D			6.6			0.260
E			8.5			0.334
F			9.4			0.370
G	5.08			0.200		
Н			1.2			0.047
I			0.9			0.035
L			45° ((typ.)		



4

2N2905AHR Revision history

4 Revision history

Table 5. Document revision history

Date	Revision	Changes	
14-Jan-2009	1	Initial release	
05-Jan-2010	2	Modified Table 1 on page 1	

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